

# HIGH FLOW Gas Flow Controller | GFC™

### EXCELLENCE IN FLOW CONTROL

Pivotal Systems' GFC™ paves the way for the future of gas flow control. The GFC™ combines Pivotal's patented, high accuracy GFM™ system with patented control valve technology. As such, it leapfrogs the current MFC technology by offering an order of magnitude improvement on key flow metrics, thereby enabling advanced wafer–manufacturing processes. At Pivotal Systems, we aim to significantly enhance fab productivity and capital efficiency by utilizing our innovative solutions.

#### Benefits of GFC™

- Highly accurate NIST traceable measurements run-to-run
- Significantly reduces downtime
- Widest flow range
- Industry's best flow accuracy for entire flow range
- Advanced flow monitoring/self-diagnosis

## **Key Features**

- No calibration ever required
- Innovative control technology
- Unaffected by variations in the upstream or downstream pressure or temperature
- No fixed orifice



# High Flow GFC Specifications (GFC5L™, GFC20L™, GFC50L™)

PERFORMANCE	Flow Range	100 sccm - 50000 sccm (3 part numbers cover this range)
	Flow Accuracy	±1% of setpoint for 10%-100% full scale: 0.5 slm - 5 slm (GFC-5L), 2.0 slm - 20 slm (GFC-20L), 5.0 slm to 50 slm (GFC-50L) ±0.25% of full scale for flows 2% to 10% full scale: 0.1 slm - 0.5 slm (GFC-5L), 0.4 slm - 2.0 slm (GFC-20L), 1.0 slm - 5.0 slm (GFC-50L)
	Repeatability	$\pm 0.25\%$ of setpoint for $10\%$ - $100\%$ full scale
	Settling Time	≤300 ms 10% - 100% full scale, ≤ 500 ms 2% - 10% full scale
	Leak Integrity	≤ 1E-9 atm • cc/sec (He)
	Leak By Rate	2.5 sccm (GFC-5L), 10.0 sccm (GFC-20L), 25.0 sccm (GFC-50L)
OPERATING CONDITIONS	Supply Pressure	Standard: 276 - 448 kPaG (40 - 65 psig)
	Downstream Pressure	Vacuum to 101 kPa (0 - 760 Torr)
	Design Pressure (Burst Pressure)	2.07 MPaG (300 psig)
	Operating Temperature	15°C - 50°C
MATERIALS	Wetted Surface	316 SS per Semi F20
	Surface Finish	5 μin average Ra
	Seals	PCTFE
ELECTRICAL	DeviceNet	11 – 24 VDC, 5 W
	Analog and RS-485	±15 VDC; 150 mA
	In-Rush Current	<200 mA